PNP/NPN Epitaxial Planar Silicon Transistors



2SB1234/2SD1851

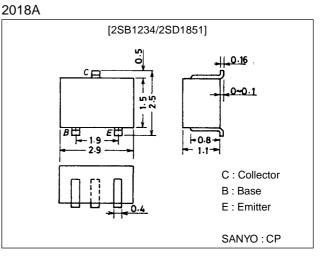
Driver Applications

Features

- · AF amplifier, solenoid drivers, LED drivers.
- · Darlington connection.
- · High DC current gain.
- Very small-sized package permitting sets to be made smaller and slimer.

Package Dimensions

unit:mm



():2SB1234

Specifications

Absolute Maximum Ratings at Ta = 25°C

Parameter	Symbol	Conditions	Ratings	Unit
Collector-to-Base Voltage	V _{CBO}		(–)80	V
Collector-to-Emitter Voltage	VCEO		(–)50	V
Emitter-to-Base Voltage	V _{EBO}		(–)10	V
Collector Current	۱ _C		(–)200	mA
Collector Current (Pulse)	I _{CP}		(-)400	mA
Collector Dissipation	PC		200	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta = 25°C

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Collector Cutoff Current	ICBO	V _{CB} =(-)60V, I _E =0			(–)100	nA
Emitter Cutoff Current	IEBO	V _{EB} =(-)8V, I _C =0			(–)100	nA
DC Current Gain	h _{FE} 1	V _{CE} =(-)2V, I _C =(-)10mA	5000			
	h _{FE} 2	V _{CE} =(-)2V, I _C =(-)100mA	4000			
			(3000)			
Collector-to-Emitter Saturation Voltage	V _{CE(sat)}	I _C =(-)100mA, I _B =(-)100µA		(–)0.9	(–)1.5	V
Base-to-Emitter Saturation Voltage	V _{BE(sat)}	I _C =(-)100mA, I _B =(-)100µA		(–)1.5	(–)2.0	V

Marking : 2SB1234 : PL 2SD1851 · XY

25D1851 : X I

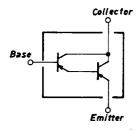
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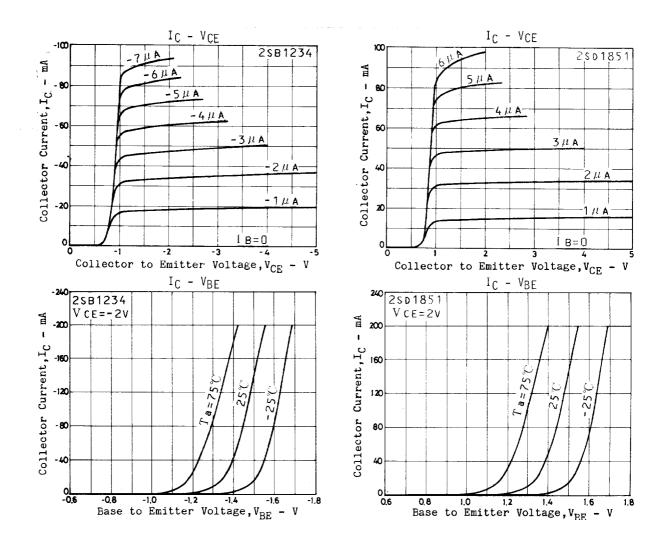
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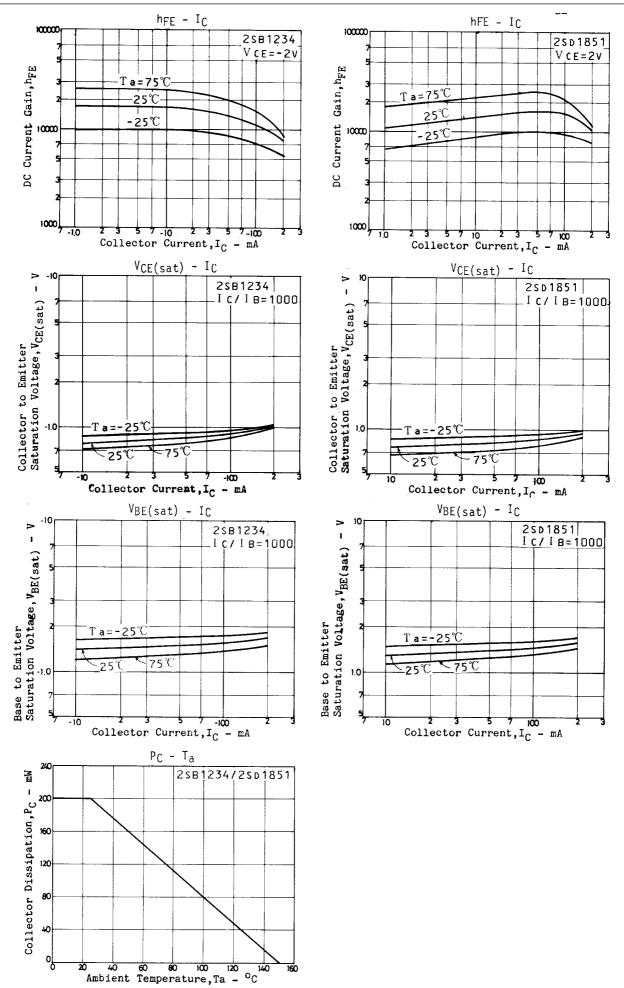
Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	Unit
Collector-to-Base Breakdown Voltage	V(BR)CBO	I _C =(-)10μΑ, I _E =0	(–)80			V
Collector-to-Emitter Breakdown Voltage	V(BR)CEO	I _C =(−)1mA, R _{BE} =∞	(–)50			V
Emitter-to-Base Breakdown Voltage	V _{(BR)EBO}	I _C =(-)10μA, I _C =0	(–)10			V

Electrical Connection



(For NPN, the polarity is reversed.)





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